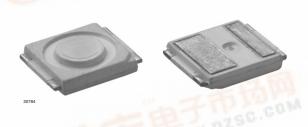
Vishay Semiconductors

# Little Star<sup>®</sup> 1 W Power SMD LED White



### **DESCRIPTION**

The VLMW711. is one of the most robust and light efficient LEDs in the market. With its extremely high level of brightness and the ultra low high profile, which is only 1.5 mm are highly suitable for both conventional lighting and specialized application such as automotive signal lights, traffic lights, channel lights, tube lights and garden lights among others.

## **PRODUCT GROUP AND PACKAGE DATA**

Product group: LEDPackage: SMD Little StarProduct series: power

Angle of half intensity: ± 60°

#### **FEATURES**

- Super high brightness surface mount LED
- High flux output; typical 90 lm
- 120° viewing angle
- Compact package outline (L x W x H) of 6.0 x 6.0 x 1.5 mm
- Ultra low height profile 1.5 mm
- Designed for high current drive; up to 350 mA
- Low thermal resistance; R<sub>th,IP</sub> = 10 K/W
- Qualified according to JEDEC moisture sensitivity level 2a
- Compatible to IR reflow soldering
- Little Star<sup>®</sup> are class 1M LED products. Do not view directly with optical instrument
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC
- Automotive qualified AEC-Q101
- ESD-withstand voltage: up to 2 kV according to JESD22-A114-B

#### **APPLICATIONS**

- Automotive: exterior applications, e.g.: fog-lamp, rear mirror lighting, etc.
- Communication: flashLED
- Industry: white goods (e.g.: oven, microwave, etc.)
- Lighting: garden light, architecture lighting, general lighting, etc.

PART	LUMINOUS FLUX CORRELATION BETWEEN LUM. FLUX/LUM. INTENSITY (at I <sub>F</sub> = 350 mA)	COLOR, LUMINOUS INTENSITY (at I <sub>F</sub> = 350 mA)	TECHNOLOGY
VLMW711U2U3XV-GS08	White, $\phi$ = (87 400 to 113 600) mlm	I <sub>V typ.</sub> = 29 700 mcd	InGaN



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ABSOLUTE MAXIMUM RAT	INGS <sup>1)</sup> VLMW711U2U3)	KV		
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Forward current		I <sub>F</sub>	350	mA
Power dissipation		P <sub>tot</sub>	1.4	W
Junction temperature		T <sub>j</sub>	+ 120	°C
Surge current t < 10 µs, d = 0.1		I <sub>FM</sub>	1000	mA
Operating temperature range		T <sub>amb</sub>	- 40 to + 100	°C
Storage temperature range		T <sub>stg</sub>	- 40 to + 100	°C
Thermal resistance junction/pin		R <sub>thJP</sub>	10	K/W

Note:

Not designed for reverse operation

<sup>1)</sup> T<sub>amb</sub> = 25 °C, unless otherwise specified

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous flux/luminous intensity	1 - 250 mA	ф	87 400		113 600	600 mlm mcd
Luminous flux/luminous intensity	$I_F = 350 \text{ mA}$	I <sub>V</sub>		29 700		
Chromaticity coordinate x acc. to CIE 1931	I <sub>F</sub> = 350 mA	х		0.33		
Chromaticity coordinate y acc. to CIE 1931	I <sub>F</sub> = 350 mA	у		0.33		
Angle of half intensity	I <sub>F</sub> = 350 mA	φ		± 60		deg
Forward voltage <sup>2)</sup>	I <sub>F</sub> = 350 mA	V <sub>F</sub>	3	3.5	4	V
Temperature coefficient of V <sub>F</sub>	I <sub>F</sub> = 350 mA	TC <sub>VF</sub>		- 3		mV/k
Temperature coefficient of I <sub>V</sub>	$I_{\rm F} = 350 \; {\rm mA}$	TC <sub>IV</sub>		- 0.4		%/K

#### Note

 $<sup>^{2)}</sup>$  Forward voltages are tested at a current pulse duration of 1 ms and a tolerance of  $\pm$  0.05 V

LUMINOUS INTENSITY/FLUX	CLASSIFICATION WHITE	
GROUP	LUMINOUS FLUX $\phi_{f V}$ (m	lm) CORRELATION TABLE
STANDARD	MIN.	MAX.
U2	87 400	99 400
U3	99 400	113 600

## Note:

Luminous intensity is tested at a current pulse duration of 25 ms and an accuracy of  $\pm$  11 %.

The above type numbers represent the order groups which include only a few brightness groups. Only one group will be shipped on each reel (there will be no mixing of two groups on each reel).

In order to ensure availability, single brightness groups will not be orderable.

In a similar manner for colors where wavelength groups are measured and binned, single wavelength groups will be shipped in any one reel. In order to ensure availability, single wavelength groups will not be orderable.

 $<sup>^{1)}</sup>$  T<sub>amb</sub> = 25 °C, unless otherwise specified



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Bin	Сх	Су
= :::	0.301	0.342
	0.314	0.353
XM	0.315	0.343
	0.303	0.333
	0.301	0.342
	0.303	0.333
XN	0.315	0.343
	0.316	0.332
	0.305	0.322
	0.303	0.333
хо	0.305	0.322
	0.316	0.332
	0.318	0.319
	0.308	0.311
	0.305	0.322
<u> </u>	0.308	0.311
	0.318	0.319
XP	0.320	0.301
	0.311	0.293
	0.308	0.311
	0.314	0.353
	0.329	0.366
WM	0.329	0.354
	0.315	0.343
	0.314	0.353
	0.315	0.343
14/1	0.329	0.354
WN	0.329	0.343
	0.316	0.332
	0.315	0.343
	0.316 0.329	0.332 0.343
WO	0.329	
WO	0.329	0.330 0.319
	0.318	0.319
	0.316	0.332
	0.316	0.330
WP	0.329	0.330
**1	0.319	0.310
	0.318	0.319
	0.319	0.310
	0.329	0.319
WQ	0.330	0.311
	0.320	0.301
	0.319	0.310
	0.329	0.366
	0.348	0.383
VM	0.347	0.368
	0.329	0.354
	0.329	0.366
	0.329	0.354
	0.347	0.368
VN	0.346	0.357
	0.329	0.343
	0.329	0.354
	0.329	0.343
	0.346	0.357
VO	0.344	0.343
	0.329	0.330
	0.329	0.343
	0.329	0.330
	0.344	0.343
VP	0.343	0.331
	0.329	0.319
	0.329	0.330

Note:

Chromaticity coordinate groups are tested at a current pulse duration of 25 ms and a tolerance of  $\pm$  0.01.

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### **TYPICAL CHARACTERISTICS**

T<sub>amb</sub> = 25 °C, unless otherwise specified

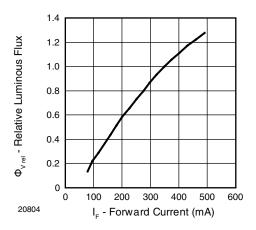


Figure 1. Relative Luminous Flux vs. Forward Current

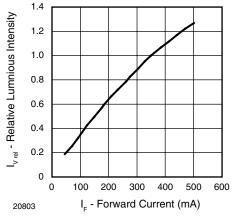


Figure 2. Relative Luminous Intensity vs. Forward Current

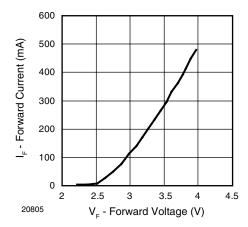


Figure 3. Forward Current vs. Forward Voltage

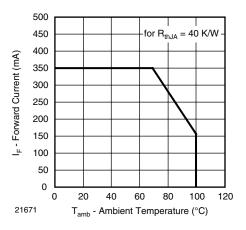


Figure 4. Max. Permissible Forward Current vs.
Ambient Temperature

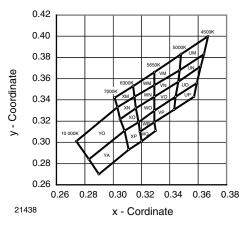


Figure 5. Coordinates of Color Groups

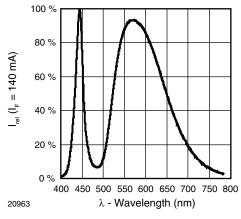


Figure 6. Relative Spectrale Emission

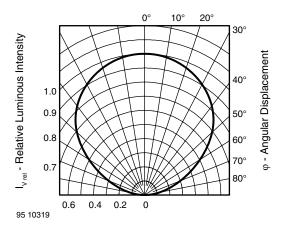
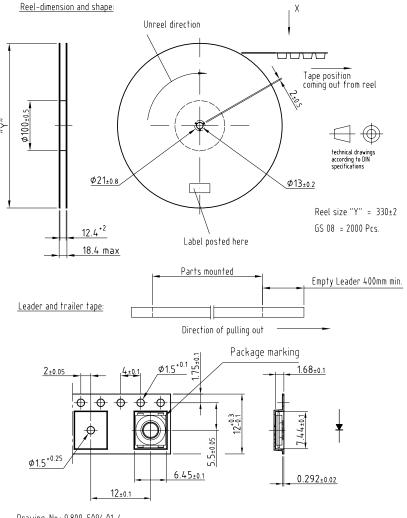


Figure 7. Relative Luminous Intensity vs. Angular Displacement

## **TAPING DIMENSIONS** in millimeters



Drawing-No.: 9.800-5094.01-4

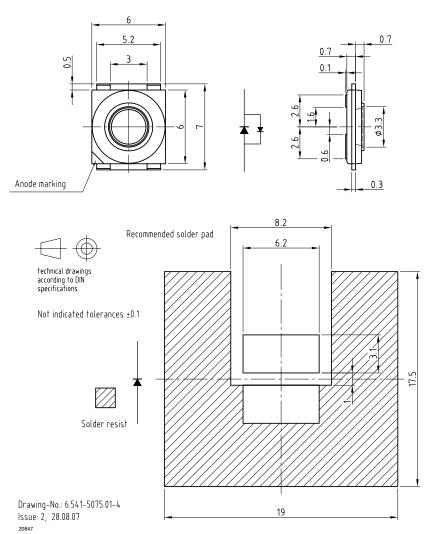
Issue: 3; 22.01.08

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## PACKAGE DIMENSIONS/SOLDERING PADS DIMENSIONS in millimeters



## **SOLDERING PROFILE**

# IR Reflow Soldering Profile for Lead (Pb)-free Soldering Preconditioning acc. to JEDEC Level 2a

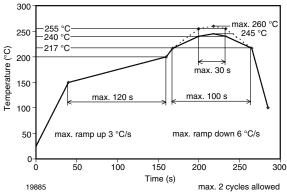
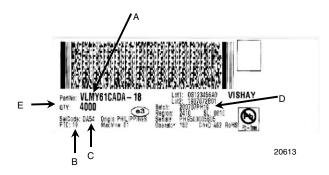


Figure 8. Vishay Lead (Pb)-free Reflow Soldering Profile (acc. to J-STD-020C)

## Vishay Semiconductors

## BAR CODE PRODUCT LABEL EXAMPLE:



A) Type of component

B) Manufacturing plant

C) SEL - selection code (bin):

e.g.: DA = code for luminous intensity group

5 = code for color group

D) Batch:

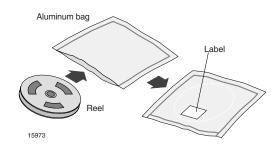
200707 = year 2007, week 07

PH19 = plant code

E) Total quantity

### **DRY PACKING**

The reel is packed in an anti-humidity bag to protect the devices from absorbing moisture during transportation and storage.



#### **FINAL PACKING**

The sealed reel is packed into a cardboard box. A secondary cardboard box is used for shipping purposes.

#### **RECOMMENDED METHOD OF STORAGE**

Dry box storage is recommended as soon as the aluminum bag has been opened to prevent moisture absorption. The following conditions should be observed, if dry boxes are not available:

- Storage temperature 10 °C to 30 °C
- Storage humidity ≤ 60 % RH max.

After more than 672 h under these conditions moisture content will be too high for reflow soldering.

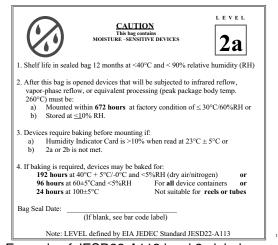
In case of moisture absorption, the devices will recover to the former condition by drying under the following condition:

192 h at  $40 \,^{\circ}\text{C} + 5 \,^{\circ}\text{C/-} \, 0 \,^{\circ}\text{C}$  and  $< 5 \,^{\circ}\text{KH}$  (dry air/nitrogen) or

96 h at 60  $^{\circ}$ C + 5  $^{\circ}$ C and < 5  $^{\circ}$ RH for all device containers or

24 h at 100 °C + 5 °C not suitable for reel or tubes.

An EIA JEDEC standard JESD22-A112 level 2a label is included on all dry bags.



Example of JESD22-A112 level 2a label

#### **ESD PRECAUTION**

Proper storage and handling procedures should be followed to prevent ESD damage to the devices especially when they are removed from the antistatic shielding bag. Electro-static sensitive devices warning labels are on the packaging.

## VISHAY SEMICONDUCTORS STANDARD BAR CODE LABELS

The Vishay Semiconductors standard bar code labels are printed at final packing areas. The labels are on each packing unit and contain Vishay Semiconductors specific data.



Vishay

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